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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/028,433	12/28/2001	Young-Sang Byun	3430-0175P	4398	
2292 75	90 01/11/2005		EXAM	EXAMINER	
BIRCH STEWART KOLASCH & BIRCH			DUONG,	DUONG, THOI V	
PO BOX 747 FALLS CHURG	CH, VA 22040-0747		ART UNIT	PAPER NUMBER	
			2871		
			DATE MAILED: 01/11/2005	5	

Please find below and/or attached an Office communication concerning this application or proceeding.

•	Application No.	Applicant(s)	
<b>A</b> 600	10/028,433	BYUN ET AL.	
Office Action Summary	Examiner	Art Unit	
	Thoi V Duong	2871	
The MAILING DATE of this communication ap Period for Reply	pears on the cover sheet wi	th the correspondence address	;
A SHORTENED STATUTORY PERIOD FOR REP THE MAILING DATE OF THIS COMMUNICATION  - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication.  - If the period for reply specified above is less than thirty (30) days, a re  - If NO period for reply is specified above, the maximum statutory period  - Failure to reply within the set or extended period for reply will, by statu  - Any reply received by the Office later than three months after the mailing  - earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a r ply within the statutory minimum of thirt d will apply and will expire SIX (6) MON te, cause the application to become AE	reply be timely filed  ty (30) days will be considered timely.  ITHS from the mailing date of this communi  BANDONED (35 U.S.C. § 133).	ication.
Status	•		
1) Responsive to communication(s) filed on 22	October 2004		
· · · · · · · · · · · · · · · · · · ·	is action is non-final.		
3) Since this application is in condition for allow.		ers, prosecution as to the mer	its is
closed in accordance with the practice under	•	•	
Disposition of Claims			
4)⊠ Claim(s) <u>1,2,4-10 and 12-16</u> is/are pending ir	the application.		
4a) Of the above claim(s) is/are withdra			
5) Claim(s) is/are allowed.			
6)⊠ Claim(s) <u>1,2,4-10 and 12-16</u> is/are rejected.			
7) Claim(s) is/are objected to.			
8) Claim(s) are subject to restriction and/	or election requirement.		
Application Papers		•	
9) The specification is objected to by the Examir	ier.		
10)⊠ The drawing(s) filed on <u>28 December 2001</u> is		objected to by the Examiner.	
Applicant may not request that any objection to the	•	·	
Replacement drawing sheet(s) including the corre	• • • • • • • • • • • • • • • • • • • •	• •	21(d).
11) The oath or declaration is objected to by the E	•		
Priority under 35 U.S.C. § 119			
12)⊠ Acknowledgment is made of a claim for foreig	n priority under 25 I LS C. A	\$ 110(a) (d) or (f)	
a)⊠ All b)□ Some * c)□ None of:	in priority under 35 O.S.C. §	; 119(a)-(u) or (i).	
1. ☐ Certified copies of the priority documer	nts have been received		
2. ☐ Certified copies of the priority documer		polication No	
3. ☐ Copies of the certified copies of the pri			_
application from the International Bure		received in this realional olage	
* See the attached detailed Office action for a lis	, , , , , , , , , , , , , , , , , , , ,	received.	
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Attachment(s)	<b>.</b> П	O(DTO 440)	
1) Motice of References Cited (PTO-892)  Discrete: Notice of Draftsperson's Patent Drawing Review (PTO-948)		Summary (PTO-413) s)/Mail Date	
3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08	3) 5) Notice of I	nformal Patent Application (PTO-152)	
Paper No(s)/Mail Date	6) 🔲 Other:	<u>_</u> ·	

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### **DETAILED ACTION**

1. This office action is in response to the Amendment filed October 22, 2004.

Accordingly, claims 1, 2, 9, 10 and 14 were amended, claims 3 and 11 were cancelled, and new claims 15 and 16 were added. Currently, claims 1, 2, 4-10 and 12-16 are pending in this application.

## Response to Arguments

2. Applicant's arguments with respect to claims 1 and 9 have been considered but are most in view of the new ground(s) of rejection.

## Claim Rejections - 35 USC § 103

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claims 1, 2 and 4-6 are rejected under 35 U.S.C. 103(a) as being unpatentable over von Gutfeld et al. (von Gutfeld, USPN 6,055,035) in view of Gyoda (Pub. No. US 2002/0063842 A1).

Re claim 1, as shown in Figs. 2A, 2B and 3, von Gutfeld discloses a method of forming a liquid crystal layer on a substrate 1A having a sealed pattern (col. 7, lines 24-27), comprising:

preparing a liquid crystal material in a projecting portion 20 having a nozzle plate 21 containing a plurality of orifices 21;

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applying a pressure to the projecting portion so as to emit the liquid crystal material simultaneously from the plurality of orifices 21 (col. 5, lines 11-65);

moving the substrate 1A in one direction (col. 6, lines 8-14); and

depositing the liquid crystal material emitted simultaneously from the plurality of orifices uniformly onto the substrate during the movement of the substrate in the one direction and applying a voltage to the projecting portion to adjust the volume of the emitted liquid crystal material according to a position of the moving substrate (Fig. 2B and col. 5, lines 50-58),

wherein, re claim 2, said nozzle plate adjusts the applied pressure for emitting the liquid crystal material (col. 5, lines 50-58 and col. 7, lines 47-55);

wherein, re claim 4, the liquid crystal material is emitted and deposited in a vacuum chamber 60 (Figs. 6 and 7, and col. 7, lines 36-55); and

wherein, as shown in Figs. 2B and 3, the volume of the emitted liquid crystal material is adjusted by a CPU 25 to obtain the correct a correct amount of the liquid crystal material deposited on the panel 1A according to a position of the nozzle plate 21 or the moving substrate (col. 5, line 50 through col. 6, line 14).

Accordingly, re claim 15, it is obvious that the CPU 25 is operated by an on-off of a voltage according to a position of the nozzle plate 21 or the moving substrate so as to allow a uniform amount of the liquid crystal material to be ejected through the nozzle plate (col. 5, line 50 through col. 6, line 14).

Von Gutfeld discloses a method of forming a liquid crystal layer on a substrate that is basically the same as that recited in claim 1 except for applying a vibration and

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pressure to the projecting portion to emit the liquid crystal material from the projection portion.

As shown in Figs. 4, 6 and 7, Gyoda discloses a method of forming a liquid crystal layer 13 on a counter substrate 112A having a sealed pattern 14A, comprising (paragraphs 108-110, page 9):

applying a vibration and pressure to a projecting portion 50 (ink-jet nozzle) through a vibrator 52 so as to emit a liquid crystal material 61 from the projecting portion,

wherein, re claim 5, the vibration is generated by a voltage applied to a resonator 59; and

wherein, re claim 6, the generated vibration is transmitted to the projecting portion through a resonating plate 52.

Thus, it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the method of forming a liquid crystal layer on a substrate of von Gutfeld with the teaching of Gyoda by employing the ink-jet application method for applying a vibration and pressure to the projection portion to discharge the liquid crystal material with high accuracy (page 8, paragraph 107).

5. Claims 9, 10, 12-14 and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Gyoda (Pub. No. US 2002/0063842 A1) in view of von Gutfeld et al. (von Gutfeld, USPN 6,055,035) and Hashimoto et al. (USPN 6,583,848 B2).

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Re claims 9 and 10, Gyoda discloses an apparatus of forming a liquid crystal layer on a substrate having a seal pattern as shown in Figs. 6 and 7, comprising (paragraphs 108-110, page 9):

a projecting portion 50 having a nozzle plate 51 containing a nozzle aperture 57 for emitting a liquid crystal material 61;

a resonator 59 for generating a vibration; and

a resonating plate 52 for transmitting the vibration to the projecting portion.

wherein the nozzle plate adjusts the applied pressure for emitting the liquid crystal material (paragraph 108); and

wherein a voltage is applied to the resonator to adjust the volume of the emitted liquid crystal material (paragraph 109).

Re claim 14, voltage means are provided for generating vibration in the resonator (paragraph 109).

Re claim 13, the apparatus further comprises a vacuum chamber for encompassing the projecting portion, the resonator and the resonating plate (paragraph 98, page 8).

Gyoda discloses an apparatus of forming a liquid crystal layer on a substrate having a seal pattern that is basically the same as that recited in claim 9 except for a nozzle plate containing a plurality of orifices simultaneously emitting a liquid crystal material and a stage for moving the substrate in one direction during continuously emitting of the liquid crystal material simultaneously from the projecting portion uniformly onto the substrate.

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At first, as shown in Figs. 2A and 2B, von Gutfeld discloses a projecting portion having a nozzle plate 21 containing a plurality of orifices simultaneously emitting a liquid crystal material (col. 5, lines 11-65),

wherein, as shown in Figs. 2B and 3, the volume of the emitted liquid crystal material is adjusted by a CPU 25 to obtain the correct a correct amount of the liquid crystal material deposited on the panel 1A according to a position of the nozzle plate 21 or the moving substrate; accordingly, it is obvious that the CPU 25 is operated by an on-off of a voltage according to a position of the nozzle plate 21 or the moving substrate so as to allow a uniform amount of the liquid crystal material to be ejected through the nozzle plate (col. 5, line 50 through col. 6, line 14).

Further, as shown in Figs. 12-15, Hashimoto et al. discloses a manufacturing apparatus of a liquid crystal device having:

a stage 31 used for mounting a substrate 21a; and

re claims 12 and 16, a driving mechanism comprising a driving source 36 for driving the stage and a position detector 37 (a photosensor or a limit switch) for sending a control signal to the driving source 37 (col. 13, lines 45-53 through col. 14, lines 12-15). Accordingly, it is obvious that the driving source is operated by a voltage which is adjusted on or off in accordance with a control signal from the position detector used to detect a position of the moving substrate mounted on the stage.

Thus, it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the apparatus for forming a liquid crystal layer on a substrate having a seal pattern of Gyoda with the teachings of von Gutfeld and

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Hashimoto by providing a nozzle plate containing a plurality of orifices simultaneously emitting a liquid crystal material to allow a uniform amount of liquid crystal material per unit area to be ejected on the substrate (von Gutfeld, col. 5, lines 30-37) and a stage for moving the substrate in one direction during emitting of the liquid crystal material simultaneously from the projecting portion uniformly onto the substrate and means for moving the stage, wherein an on-off of a voltage applied to the apparatus is adjusted according to a position of the moving substrate so as to produce a mass-production of liquid crystal display devices (Hashimoto, col. 3, lines 13-1).

6. Claims 7 and 8 are rejected under 35 U.S.C. 103(a) as being unpatentable over von Gutfeld et al. (von Gutfeld, USPN 6,055,035) in view of Gyoda (Pub. No. US 2002/0063842 A1) as applied to claims 1, 2 and 4-6 and further in view of Masazumi et al. (Masazumi, USPN 6,331,884 B1).

The method of forming a liquid crystal layer of von Gutfeld as modified in view of Gyoda above includes all that is recited in claims 7 and 8 except for forming a black matrix under the sealed pattern, wherein the liquid crystal material start and stop is deposited on the black matrix.

As shown in Fig. 5, Masazumi discloses a black matrix 8 (black light absorbing layer) formed under a sealed pattern 9b' (col. 16, lines 18-23), wherein a liquid crystal material 9a, 9a', 9a'' start and stop is deposited on the black matrix.

Thus, it would have been obvious to one having ordinary skill in the art at the time the invention was made to further modify the method of von Gutfeld with the teaching of Masazumi by formed a black matrix under a sealed pattern for enabling

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display of a black which is background color when the liquid crystal is transparent (col. 10, lines 1-10).

#### Conclusion

7. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

8. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thoi V. Duong whose telephone number is (571) 272-2292. The examiner can normally be reached on Monday-Friday from 8:30 am to 4:30 pm. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Robert Kim, can be reached at (571) 272-2293.

Thoi Duong 5

TARIFUR R. CHOWDHURY